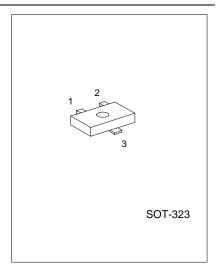
## **DTA115E**

### PNP EPITAXIAL SILICON TRANSISTOR

# PNP DIGITAL TRANSISTOR (BUILT-IN RESISTORS)

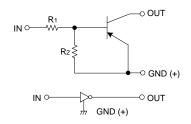
#### **■ FEATURES**

- \*Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see the equivalent circuit).
- \*The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input They also have the advantage of almost completely eliminating parasitic effects.
- \*Only the on / off conditions need to be set for operation, making device design easy.



\*Pb-free plating product number:DTA115EL

#### **■ EQUIVALENT CIRCUIT**



#### PIN CONFIGURATION

PIN NO.	PIN NAME
1	GND
2	IN
3	OUT

#### **■ ORDERING INFORMATION**

Order Number		Dookogo	Packing	
Normal	Lead free	Package	Packing	
DTA115E-AL3-R	DTA115EL-AL3-R	SOT-323	Tape Reel	

#### **■ MARKING**



#### ■ ABSOLUATE MAXIUM RATINGS (Ta = 25°C)

PARAMETER	SYMBOL RATINGS		UNIT	
Supply Voltage	V <sub>CC</sub> -50		V	
Input Voltage	V <sub>IN</sub>	V <sub>IN</sub> -40~+10		
Output Current	l <sub>out</sub>	-20	Л	
	I <sub>c(max)</sub>	-100	mA mA	
Power Dissipation	P <sub>D</sub> 200		mW	
Junction Temperature	T <sub>J</sub> 150		$^{\circ}$	
Storage Temperature	T <sub>STG</sub>	-40 ~ <b>+</b> 150	$^{\circ}\mathbb{C}$	

#### ■ ELECTRICAL CHARACTERISTICS (Ta= 25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	V <sub>IN(off)</sub>	$V_{CC}$ = -5V, $I_{OUT}$ =-100 $\mu$ A			-0.5	V
	V <sub>IN(ON)</sub>	$V_{OUT}$ = -0.3 $V$ , $I_{OUT}$ = -1 $mA$	-3			V
Output Voltage	V <sub>OUT(ON)</sub>	$I_{OUT}$ = -5mA, $I_{IN}$ = -0.25 mA		-0.1	-0.3	V
Input Current	I <sub>IN</sub>	$V_{IN} = -5V$			-0.15	mA
Output Current	I <sub>OUT(off)</sub>	V <sub>CC</sub> = -50V , V <sub>IN</sub> =0V			-0.5	$\mu$ A
DC Current Gain	Gı	$V_{OUT}$ = -5 $V$ , $I_{OUT}$ = -5 $MA$	82			
Input Resistance	R <sub>1</sub>		70	100	130	$\mathbf{k}\Omega$
Resistance Ratio	R <sub>2</sub> /R <sub>1</sub>		0.8	1	1.2	
Transition Frequency	f <sub>T</sub>	$V_{CE}$ = -10 V, $I_{E}$ = 5mA, $f$ =100MHz *		250		MHz

<sup>\*</sup>Transition frequency of the device

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